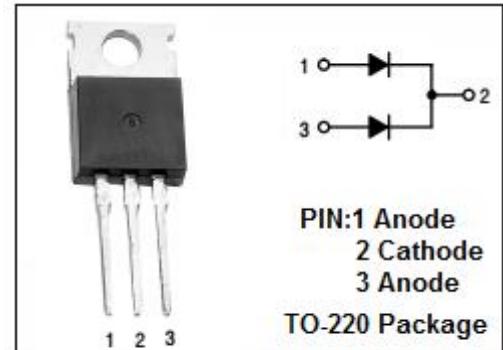


Schottky Barrier Rectifier

STPS30150CT

FEATURES

- With TO-220 packaging
- High Junction Temperature Capability
- Low forward voltage, high current capability
- High current capability
- Low power loss, high efficiency
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

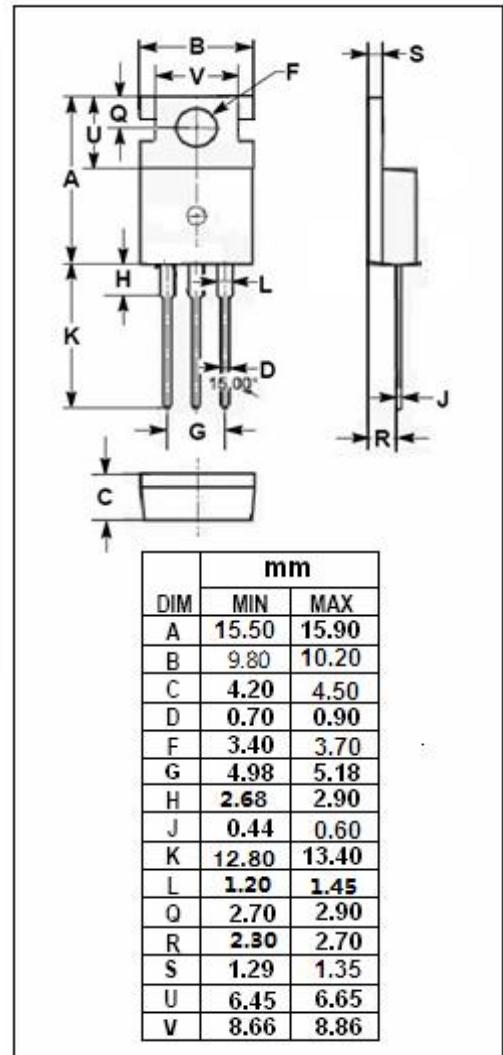


APPLICATIONS

- Switching power supply
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{RRM}	Peak Repetitive Reverse Voltage		
V_{RMS}	RMS Voltage	150	V
V_R	DC Blocking Voltage		
$I_{F(AV)}$	Average Rectified Forward Current @ $T_c=110^\circ\text{C}$	15	A
I_{FSM}	RMS Forward Current	30	A
I_{FSM}	Nonrepetitive Peak Surge Current (10ms single half sine-wave superimposed on rated load conditions)	220	A
T_J	Junction Temperature	-55~150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55~175	$^\circ\text{C}$



Schottky Barrier Rectifier**STPS30150CT****THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.6	°C/W

ELECTRICAL CHARACTERISTICS (Pulse Test: Pulse Width=300 μ s,Duty Cycle≤1%)

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
V _F	Maximum Instantaneous Forward Voltage	I _F = 15A ;T _c = 25°C I _F = 15A ;T _c = 125°C I _F = 30A ;T _c = 25°C I _F = 30A ;T _c = 125°C	0.92 0.75 1.00 0.86	V
I _R	Maximum Instantaneous Reverse Current	V _R = rated V _{RRM} ; T _j = 25°C V _R = rated V _{RRM} ; T _j = 125°C	6.8 8.0	μ A mA